



STS3401A

SamHop Microelectronics Corp.

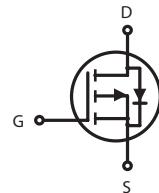
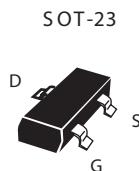
Ver 1.0

P-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (mΩ) Max
-30V	-3.2A	79 @ VGS=-10V
		127 @ VGS=-4.5V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous ^a	-3.2	A
		-2.6	A
I_{DM}	-Pulsed ^b	-12	A
P_D	Maximum Power Dissipation ^a	1.25	W
		0.8	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient ^a	100	$^\circ\text{C/W}$
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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$, $I_D=-250\mu\text{A}$	-30			V
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=-24\text{V}$, $V_{GS}=0\text{V}$			-1	uA
I _{GSS}	Gate-Body Leakage Current	$V_{GS} = \pm 20\text{V}$, $V_{DS}=0\text{V}$			± 100	nA
ON CHARACTERISTICS						
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_D=-250\mu\text{A}$	-1.0	-1.6	-3.0	V
R _{D(S(ON))}	Drain-Source On-State Resistance	$V_{GS}=-10\text{V}$, $I_D=-1.6\text{A}$		63	79	m ohm
		$V_{GS}=-4.5\text{V}$, $I_D=-1.3\text{A}$		94	127	m ohm
g _{FS}	Forward Transconductance	$V_{DS}=-5\text{V}$, $I_D=-1.6\text{A}$		6		S
DYNAMIC CHARACTERISTICS ^c						
C _{iss}	Input Capacitance	$V_{DS}=-15\text{V}$, $V_{GS}=0\text{V}$ $f=1.0\text{MHz}$		345		pF
C _{oss}	Output Capacitance			85		pF
C _{rss}	Reverse Transfer Capacitance			69		pF
SWITCHING CHARACTERISTICS ^c						
t _{D(ON)}	Turn-On Delay Time	$V_{DD}=-15\text{V}$ $I_D=-1\text{A}$ $V_{GS}=-10\text{V}$ $R_{GEN}=6\text{ ohm}$		7.2		ns
t _r	Rise Time			12.5		ns
t _{D(OFF)}	Turn-Off Delay Time			7.5		ns
t _f	Fall Time			9		ns
Q _g	Total Gate Charge	$V_{DS}=-15\text{V}$, $I_D=-1.6\text{A}$, $V_{GS}=-10\text{V}$		8.6		nC
		$V_{DS}=-15\text{V}$, $I_D=-1.6\text{A}$, $V_{GS}=-4.5\text{V}$		4.5		nC
Q _{gs}	Gate-Source Charge	$V_{DS}=-15\text{V}$, $I_D=-1.6\text{A}$, $V_{GS}=-10\text{V}$		0.55		nC
Q _{gd}	Gate-Drain Charge			2.5		nC
DRAIN-SOURCE DIODE CHARACTERISTICS						
V _{SD}	Diode Forward Voltage	$V_{GS}=0\text{V}$, $I_S=-1.6\text{A}$		-0.84	-1.2	V
Notes						
a.Surface Mounted on FR4 Board, $t \leq 10\text{sec}$.						
b.Pulse Test:Pulse Width $\leq 300\text{us}$, Duty Cycle $\leq 2\%$.						
c.Guaranteed by design, not subject to production testing.						

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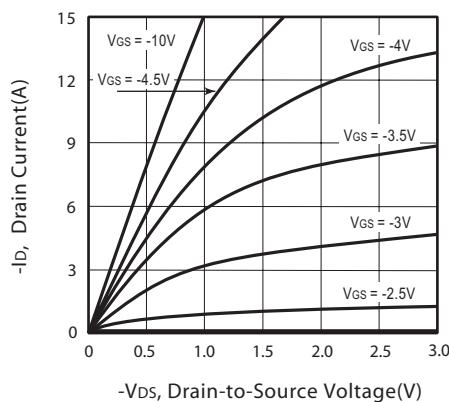


Figure 1. Output Characteristics

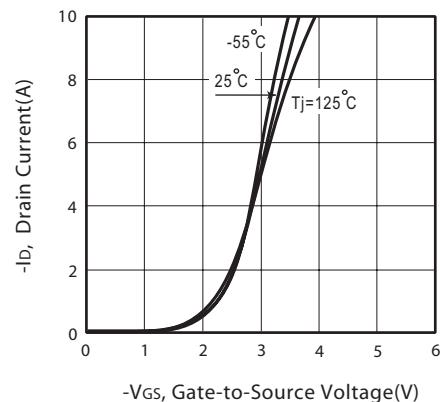


Figure 2. Transfer Characteristics

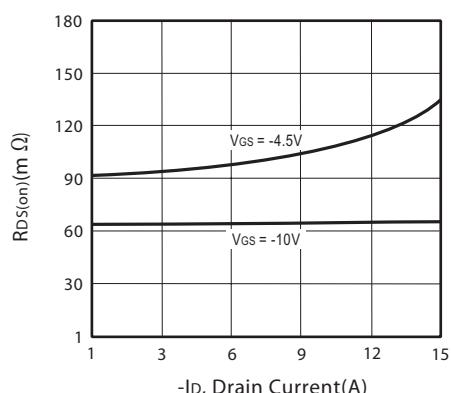


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

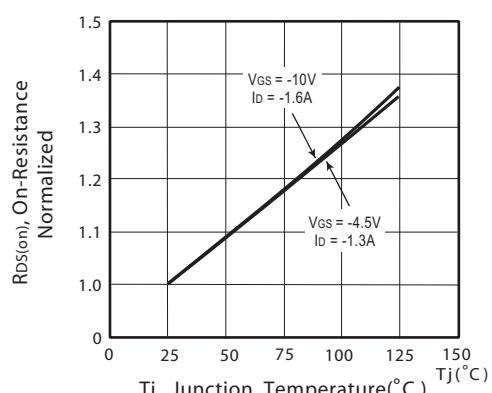


Figure 4. On-Resistance Variation with Drain Current and Temperature

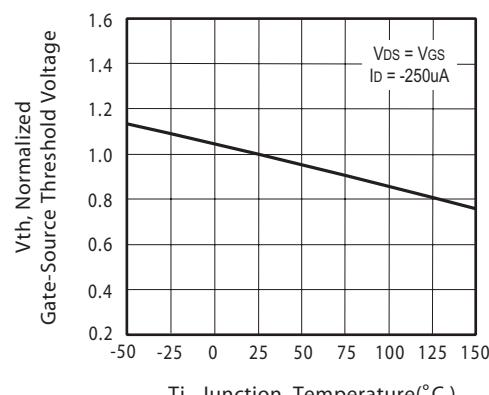


Figure 5. Gate Threshold Variation with Temperature

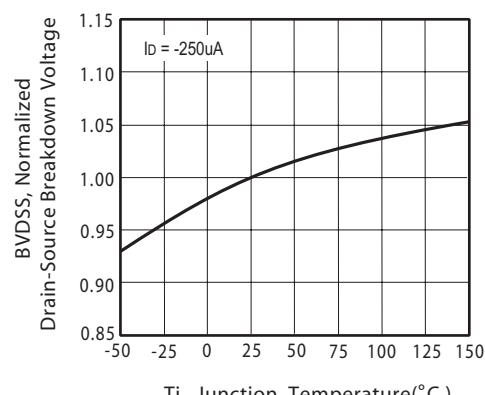


Figure 6. Breakdown Voltage Variation with Temperature

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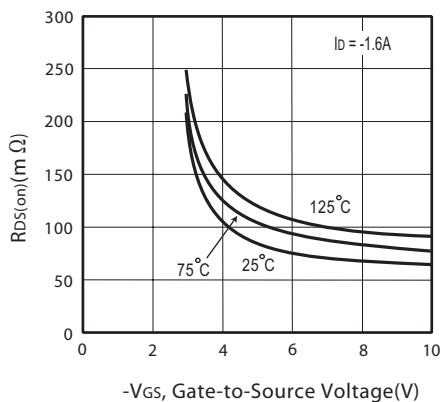


Figure 7. On-Resistance vs.
Gate-Source Voltage

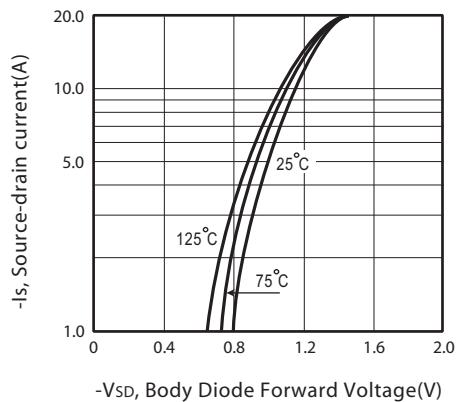


Figure 8. Body Diode Forward Voltage
Variation with Source Current

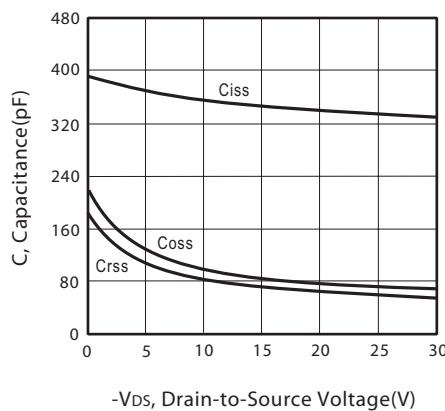


Figure 9. Capacitance

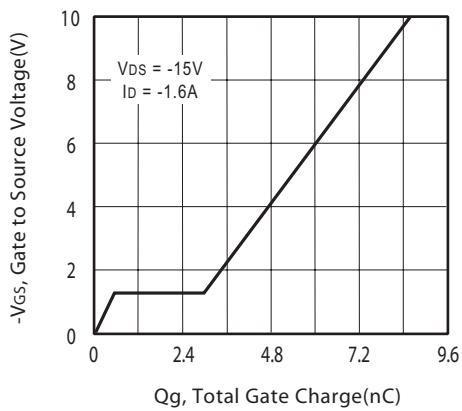


Figure 10. Gate Charge

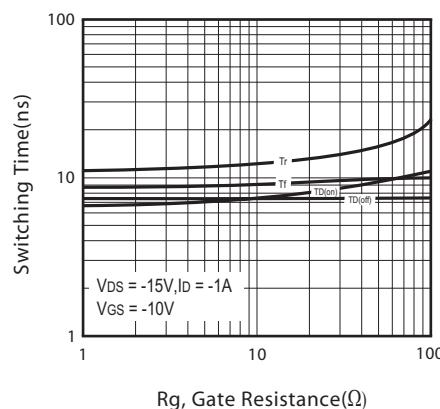


Figure 11. switching characteristics

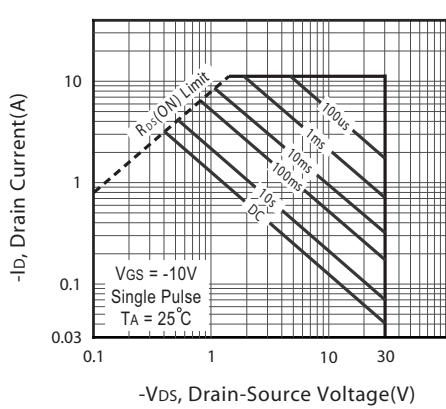


Figure 12. Maximum Safe Operating Area

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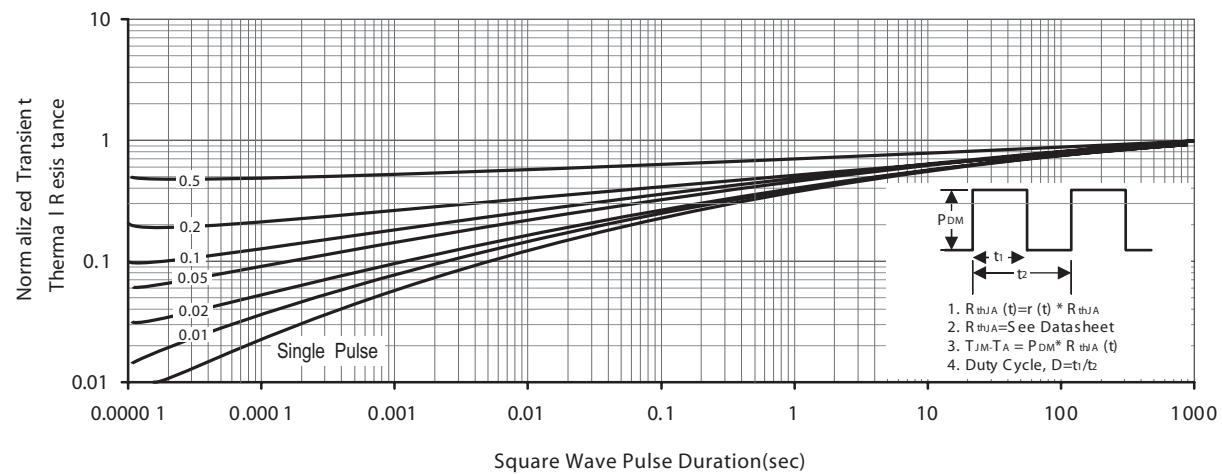


Figure 13. Normalized Thermal Transient Impedance Curve

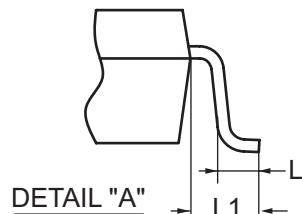
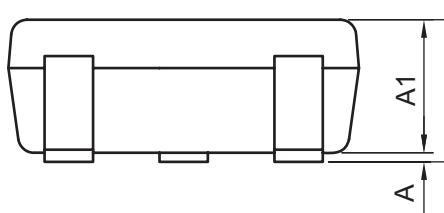
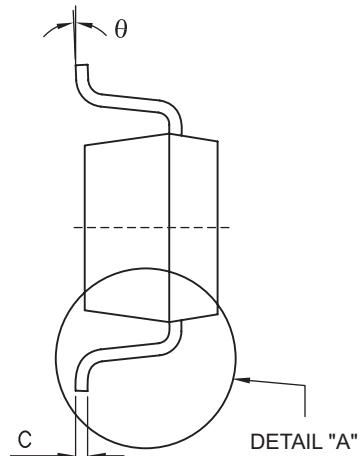
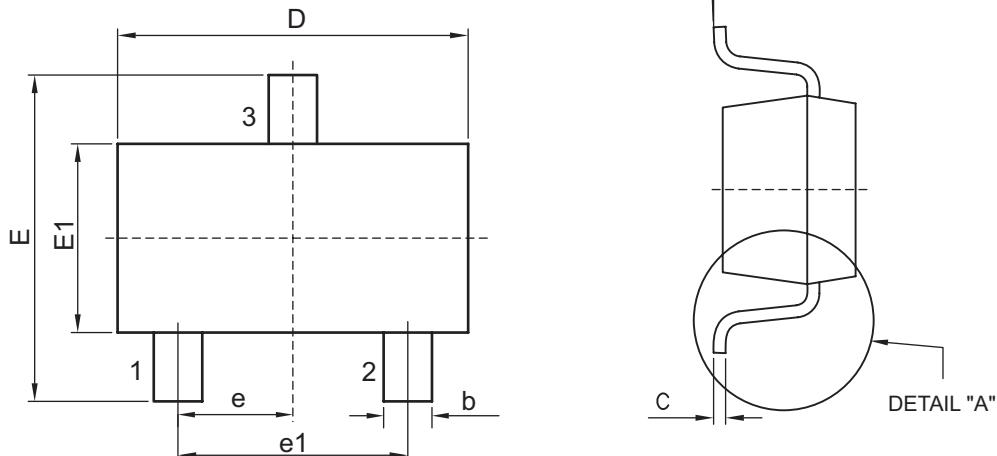
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PACKAGE OUTLINE DIMENSIONS

SOT 23



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
D	2.700	3.100	0.106	0.122
E	2.200	3.000	0.087	0.118
E1	1.200	1.700	0.047	0.067
e	0.850	1.150	0.033	0.045
e1	1.800	2.100	0.071	0.083
b	0.300	0.510	0.019	0.020
C	0.080	0.200	0.003	0.008
A	0.000	0.150	0.000	0.006
A1	0.887	1.300	0.035	0.051
L	0.450 REF.		0.018 REF.	
L1	0.600 REF.		0.024 REF.	
θ	0°	10°	0°	10°

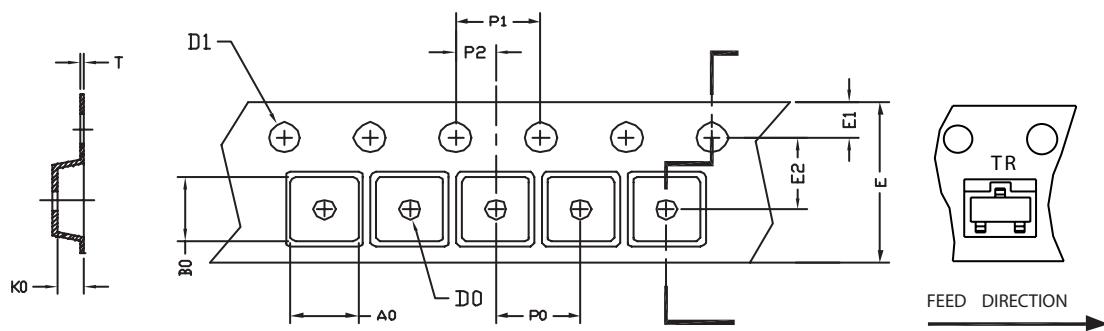
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SOT23 Tape and Reel Data

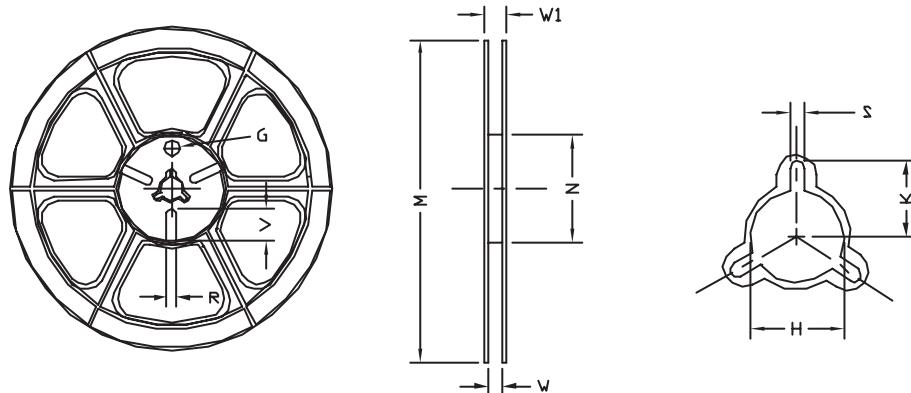
SOT23-3L Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
SOT23-3L	3.15 ±0.10	2.77 ±0.10	1.22 ±0.10	1.00 +0.05	1.50 +0.10	8.00 +0.30 -0.10	1.75 ±0.10	3.50 ±0.05	4.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.22 ±0.04

SOT23-3L Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
8mm	178	178 ±1	60 ±1	9.00 ±0.5	12.00 ±0.5	13.5 ±0.5	10.5	2.00 ±0.5	10.0	5.00	18.00

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